

	Type	L #	Hits	Search Text	DBs	Time Stamp
1	BRS	L1	627	349/38	USEA T; US-P GPUB ; EPO; JPO; DEFW ENT; IBM TDB	2001/12/2 0 08:41
2	BRS	L2	270	1 and storage	USEA T; US-P GPUB ; EPO; JPO; DEFW ENT; IBM TDB	2001/12/2 0 09:00
3	BRS	L3	4	1 and storage adj common	USEA T; US-P GPUB ; EPO; JPO; DEFW ENT; IBM TDB	2001/12/2 0 08:57
4	BRS	L4	13	1 and storage adj (line or wir\$3)	USEA T; US-P GPUB ; EPO; JPO; DEFW ENT; IBM	2001/12/2 0 10:51

	Type	L #	Hits	Search Text	DBs	Time Stamp
5	BFS	L5	405	349/39	USFA T; US-P GPUB ; EPO; JPO; DEFW ENT; IBM TDE	2002/12/2 0 09:22
6	BFS	L6	8	5 and storage adj (line\$1 or wir\$3)	USFA T; US-P GPUB ; EPO; JPO; DEFW ENT; IBM TDE	2002/12/2 0 14:55
7	BFS	L7	1	"6079365".FN.	USFA T	2002/12/2 0 09:27
8	BFS	L8	1	"6067132".FN.	USFA T	2002/12/2 0 09:28
9	BFS	L9	1	"5982460".FN.	USFA T	2002/12/2 0 09:29
10	BFS	L10	1	"5966193".FN.	USFA T	2002/12/2 0 09:29
11	BFS	L11	1	"5940181".FN.	USFA T	2002/12/2 0 09:29
12	BFS	L12	1	"5920362".FN.	USFA T	2002/12/2 0 09:29
13	BFS	L13	1	"5920362".FN.	USFA T	2002/12/2 0 09:29
14	BFS	L14	1	"5917563".FN.	USFA T	2002/12/2 0 09:31
15	BFS	L15	1	"5814529".FN.	USFA T	2002/12/2 0 09:33
				" " " "	USFA T	2002/12/2 0 09:35
				" " " "		
16	BFS	L16	1	"3414078".FN.	USFA T	2002/12/2 0 09:36
				" " " "	USFA T	2002/12/2 0 09:36
				" " " "		

	Type	L #	Hits	Search Text	DBs	Time Stamp
21	BFS	L21	1	"5182620".PN.	USPA T	2002/12/2 0 09:37
22	BFS	L22	981	349/43	USPA T; US-P GPUB ; EPO; JPO; DEFW ENT; IBM TDE	2002/12/2 0 09:41
23	BFS	L23	16	22 and storage adj (line\$1 or wir\$3)	USPA T; US-P GPUB ; EPO; JPO; DEFW ENT; IBM TDE	2002/12/2 0 10:51
24	BFS	L24	27237 2	liquid adj crystal	USPA T; US-P GPUB ; EPO; JPO; DEFW ENT; IBM TDE	2002/12/2 0 15:29
25	BFS	L25	133	24 and storage adj (line\$1 or wir\$3)	USPA T; US-P GPUB ; EPO; JPO; DEFW	2002/12/2 0 09:58

	Type	L #	Hits	Search Text	DBs	Time Stamp
26	BRS	L26	133	25 and storage adj (line\$1 or wir\$3)	USPA T; US-P GPUB ; EPO; JPO; DEFW ENT; IBM TDE	2002/12/2 0 11:27
27	BRS	L27	71	25 and storage adj (capacit\$4 or electrode\$1)	USPA T; US-P GPUB ; EPO; JPO; DEFW ENT; IBM TDE	2002/12/2 0 09:59
28	BRS	L29	0	28 and storage adj (line\$1 or wir\$3)	USPA T; US-P GPUB ; EPO; JPO; DEFW ENT; IBM TDE	2002/12/2 0 10:51
29	BRS	L28	2	5814529.pn.	USPA T; US-P GPUB ; EPO; JPO; DEFW ENT; IBM TDE	2002/12/2 0 10:52
32	BRS	L32	1	"5414278".PN.	USPA T; US-P GPUB ; EPO; JPO; DEFW ENT; IBM TDE	2002/12/2 0 10:53

	Type	L #	Hits	Search Text	DBs	Time Stamp
34	BRS	L34	1	"5247289".PN.	USPA T	2002/12/2 0 10:53
35	BRS	L35	1	"5182620".PN.	USPA T	2002/12/2 0 10:54
36	BFS	L36	11	26 and common adj wir\$3	USPA T; US-P GPUB ; EPO; CPO; DEFW ENT; IRM TDE	2002/12/2 0 11:28
37	BFS	L37	61	5 and common adj (line\$1 or wir\$3)	USPA T; US-P GPUB ; EPO; CPO; DEFW ENT; IRM TDE	2002/12/2 0 11:39
38	BFS	L38	58	37 and capacit\$4	USPA T; US-P GPUB ; EPO; CPO; DEFW ENT; IRM TDE	2002/12/2 0 11:39
39	BRS	L39	43	37 and (storage or supplement\$2 or auxiliary) adj (capacit\$4 or	USPA T; US-P GPUB ; EPO; CPO;	2002/12/2 0 11:41

	Type	L #	Hits	Search Text	DBs	Time Stamp
40	BFS	L40	6	5 and image adj sensor	USPA T; US-P GPUB ; EPO; JPO; DEFW ENT; IBM TDE	2002/12/2 0 14:56
41	BFS	L41	0	40 and magneto adj electric	USPA T; US-P GPUB ; EPO; JPO; DEFW ENT; IBM TDE	2002/12/2 0 14:56
42	BFS	L42	0	5 and magneto adj electric	USPA T; US-P GPUB ; EPO; JPO; DEFW ENT; IBM TDE	2002/12/2 0 14:57
43	BFS	L43	20	5 and bias adj voltage	USPA T; US-P GPUB ; EPO; JPO; DEFW ENT; IBM TDE	2002/12/2 0 15:01

	Type	L #	Hits	Search Text	DBs	Time Stamp
44	BPS	L44	3	43 and radiation	USPA T; US-P GPUB ; EFO; JFO; DEFW ENT; IEM TDB	2002/12/2 0 15:01
45	BFS	L45	3695	24 and image adj sensor	USPA T; US-P GPUB ; EFO; JFO; DEFW ENT; IEM TDB	2002/12/2 0 15:51
46	BFS	L46	0	45 and convert\$3 adj magnetolectric	USPA T; US-P GPUB ; EFO; JFO; DEFW ENT; IEM TDB	2002/12/2 0 15:31
47	BFS	L47	2	45 and convert\$3 adj electric adj charges	USPA T; US-P GPUB ; EFO; JFO; DEFW ENT; IEM TDB	2002/12/2 0 15:33

	Type	L #	Hits	Search Text	DBs	Time Stamp
48	BFS	L49	0	48 and bias adj voltage	USPA T; US-P GPUB ; EFO; JFO; DEFW ENT; IBM TDE	2002/12/2 0 15:34
49	BFS	L50	205	45 and (stor\$3 or convert\$3) adj electric	USFA T; US-P GPUB ; EFO; JFO; DEFW ENT; IBM TDE	2002/12/2 0 15:36
50	BFS	L51	20	50 and storage adj capacit\$4	USFA T; US-P GPUB ; EFO; JFO; DEFW ENT; IBM TDE	2002/12/2 0 15:37
51	BFS	L48	9	45 and convert\$3 adj radiation	USFA T; US-P GPUB ; EFO; JFO; DEFW ENT; IBM TDE	2002/12/2 0 15:40

	Type	L #	Hits	Search Text	DBs	Time Stamp
52	BFS	L52	8	45 and convert\$ near radiation.	USPA T; US-P GPUB ; EPO; JPO; DEFW ENT; IEM TDE	2002/12/2 0 15:58
53	BFS	L53	7	45 and convert\$ adj layer	USFA T; US-P GPUB ; EPO; JPO; DEFW ENT; IEM TDE	2002/12/2 0 16:01
54	BFS	L54	0	5 and convert\$3 adj layer	USFA T; US-P GPUB ; EPO; JPO; DEFW ENT; IEM TDE	2002/12/2 0 16:02
55	BFS	L55	0	35 and pixel adj collect\$3	USFA T; US-P GPUB ; EPO; JPO; DEFW ENT; IEM TDE	2002/12/2 0 16:03

	Type	L #	Hits	Search Text	DBs	Time Stamp
56	BFS	L55	50	5 and electric adj charg\$3	USPA T; US-P G:UB ; EFC; JFO; DEFW ENT; IEM TDE	2002/12/2 0 16:44
57	BFS	L57	0	5 and selenium	USPA T; US-P G:UB ; EFC; JFO; DEFW ENT; IEM TDE	2002/12/2 0 16:15
58	BFS	L58	45	45 and selenium	USPA T; US-P G:UB ; EFC; JFO; DEFW ENT; IEM TDE	2002/12/2 0 16:15
59	BFS	L59	12	45 and amorphous adj selenium	USPA T; US-P G:UB ; EFC; JFO; DEFW ENT; IEM TDB	2002/12/2 0 16:15

	Type	L #	Hits	Search Text	DBs	Time Stamp
60	BFS	L60	281	45 and electric adj charg\$3	USPA T; US-P GPUB ; EPO; JPO; DEFW ENT; IEM TDE	2002/12/2 0 16:26
61	BFS	L61	31	60 and bias adj voltage	USEA T; US-P GPUB ; EPO; JPO; DEFW ENT; IEM TDE	2002/12/2 0 16:26
62	BFS	L62	10	61 and storage adj capacitor	USEA T; US-P GPUB ; EPO; JPO; DEFW ENT; IEM TDE	2002/12/2 0 16:26
63	BFS	L63	6	61 and bias adj voltage	USEA T; US-P GPUB ; EPO; JPO; DEFW ENT; IEM TDE	2002/12/2 0 16:44